

November 1996

Features

- Operation from Single or Dual Supplies
- Common Mode Input Voltage Range to GND
- Output Voltage Compatible with TTL, DTL, ECL, MOS and CMOS
- Differential Input Voltage Range Equal to the Supply Voltage
- Maximum Input Offset Voltage (V_{IO})
 - CA139A, CA239A, CA339A 2mV
 - CA139, CA239, CA339 5mV
 - LM2901 7mV
 - LM3302 20mV
- Replacement for Industry Types 139, 239, 339, 139A, 239A, 339A, 2901, 3302

Applications

- Square Wave Generator
- Time Delay Generators
- Pulse Generators
- Multivibrators
- High Voltage Digital Logic Gates
- A/D Converters
- MOS Clock Timers

Description

The devices in this series consist of four independent single or dual supply voltage comparators on a single monolithic substrate. The common mode input voltage range includes ground even when operated from a single supply, and the low power supply current drain makes these comparators suitable for battery operation. These types were designed to directly interface with TTL and CMOS.

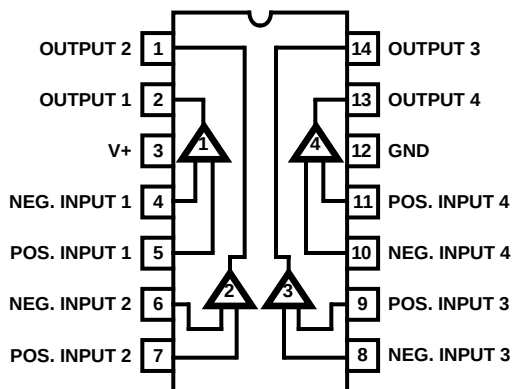
Types CA139A, CA239A, and CA339A have all the features and characteristics of their prototype counterparts CA139, CA239, and CA339 plus an even lower input offset voltage characteristic. All the SOIC parts are available on tape and reel. Replace the M suffix in the part number with M96 when ordering (e.g. CA0339AM96). The CA339 is also available in chip form (H suffix).

Ordering Information

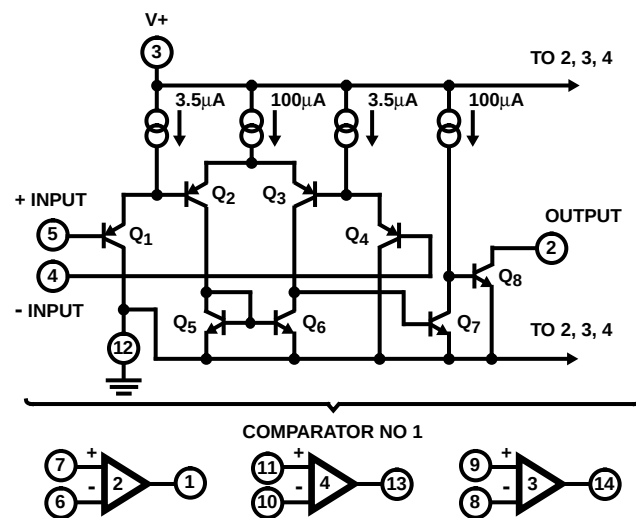
PART NO. (BRAND)	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
CA0139E	-55 to 125	14 Ld PDIP	E14.3
CA0139F	-55 to 125	14 Ld Cerdip	E14.3
CA0139M, AM (139, 139A)	-55 to 125	14 Ld SOIC	M14.15
CA0239E, AE	-25 to 85	14 Ld PDIP	E14.3
CA0239F, AF	-25 to 85	14 Ld Cerdip	E14.3
CA0239M, (239)	-25 to 85	14 Ld SOIC	M14.15
CA0339E, AE	0 to 70	14 Ld PDIP	E14.3
CA0339M, (339)	0 to 70	14 Ld SOIC	M14.15
LM339N, AN	0 to 70	14 Ld PDIP	E14.3
LM2901M (2901)	-40 to 85	14 Ld SOIC	M14.15
LM2901N	-40 to 85	14 Ld PDIP	E14.3
LM3302M (3302)	-40 to 85	14 Ld SOIC	M14.15
LM3302N	-40 to 85	14 Ld PDIP	E14.3

Pinout

CA139, CA239, CA239A (PDIP, Cerdip, SOIC)
 CA139A, CA339, CA339A, LM2901, LM3302 (PDIP, SOIC)
 LM339, LM339A (PDIP)
 TOP VIEW



Schematic Diagram



CA139, CA139A, CA239, CA239A, CA339, CA339A, LM339, LM339A, LM2901, LM3302

Absolute Maximum Ratings

Supply Voltage 36V or $\pm 18V$
Differential Input Voltage. 36V
Input Voltage. -0.3V to +36V
Input Current ($V_I < -0.3V$, Note 1) 50mA
Output Short Circuit Duration (Single Supply, Note 2) . . Continuous

Operating Conditions

Temperature Range
CA139, CA139A -55°C to 125°C
CA239, CA239A -25°C to 80°C
CA339, CA339A, LM339, LM339A 0°C to 70°C
LM2901, LM3302 -40°C to 85°C

Thermal Information

Thermal Resistance (Typical, Note 3) θ_{JA} (°C/W) θ_{JC} (°C/W)
CERDIP Package 90 30
PDIP Package 100 N/A
SOIC Package 175 N/A
Maximum Junction Temperature (Ceramic Package) 175°C
Maximum Junction Temperature (Plastic Package) 150°C
Maximum Storage Temperature Range -65°C to 150°C
Maximum Lead Temperature (Soldering 10s) 300°C
(SOIC - Lead Tips Only)

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTES:

- Inputs must not go more negative than -0.3V.
- Short circuits from the output to V+ can cause excessive heating and eventual destruction. The maximum output current independent of V+ is approximately 20mA.
- θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

Electrical Specifications V+ = 5V, Unless Otherwise Specified

PARAMETER	SYMBOL	TEST CONDITIONS	TEMP (°C)	CA139			CA139A			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	V_{IO}	$V_{REF} = 1.4V$, $R_S = 0$, Output Switch Point $V \approx 1.4V$	$T_A = 25$	-	2	5	-	1	2	mV
			Note 4	-	-	9	-	-	4	mV
Differential Input Voltage	V_{ID}	Keep All Inputs $\geq 0V$, or V- (if used), (Note 5)	Note 4	-	-	36	-	-	36	V
Saturation Voltage	V_{SAT}	$V_{I-} = 1V$, $V_{I+} = 0V$, $I_{SINK} \leq 4mA$	$T_A = 25$	-	250	400	-	250	400	mV
			Note 4	-	-	700	-	-	700	mV
Common Mode Input Voltage Range	V_{ICR}	Note 6	$T_A = 25$	0	-	V+ -1.5	0	-	V+ -1.5	V
			Note 4	0	-	V+ -2	0	-	V+ -2	V
Input Offset Current	I_{IO}	$I_{I+} - I_{I-}$	$T_A = 25$	-	3	25	-	3	25	nA
			Note 4	-	-	100	-	-	100	nA
Input Bias Current	I_{IB}	I_{I+} or I_{I-} with Output in Linear Range	$T_A = 25$	-	25	100	-	25	100	nA
			Note 4	-	-	300	-	-	300	nA
Total Supply Current	I_+	$R_L = \infty$ On All Comparators	$T_A = 25$	-	0.8	2	-	0.8	2	mA
Output Leakage Current		$V_{I+} \geq 1V$, $V_{I-} = 0V$, $V_O = 5V$	$T_A = 25$	-	0.1	-	-	0.1	-	nA
		$V_{I+} \geq 1V$, $V_{I-} = 0V$, $V_O = 30V$	Note 4	-	-	1	-	-	1	μA
Output Sink Current		$V_{I-} \geq 1V$, $V_{I+} = 0V$, $V_O \leq 1.5V$	$T_A = 25$	6	16	-	6	16	-	mA
Voltage Gain	A_{OL}	$R_L \geq 15k\Omega$, V+ = 15V	$T_A = 25$	-	200	-	50	200	-	V/mV

CA139, CA139A, CA239, CA239A, CA339, CA339A, LM339, LM339A, LM2901, LM3302

Electrical Specifications $V^+ = 5V$, Unless Otherwise Specified (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS	TEMP (°C)	CA139			CA139A			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	
Large Signal Response Time		$V_I = \text{TTL Logic Swing}$, $V_{REF} = 1.4V$, $V_{RL} = 5V$, $R_L = 5.1k\Omega$	$T_A = 25$	-	300	-	-	300	-	ns
Response Time (Figures 3, 4)		$V_{RL} = 5V$, $R_L = 5.1k\Omega$	$T_A = 25$	-	1.3	-	-	1.3	-	μs

Electrical Specifications $V^+ = 5V$, Unless Otherwise Specified

PARAMETER	SYMBOL	TEST CONDITIONS	TEMP (°C)	CA239, CA339, LM339			CA239A, CA339A, LM339A			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	V_{IO}	$V_{REF} = 1.4V$, $R_S = 0$, Output Switch Point $V \cong 1.4V$	$T_A = 25$	-	2	5	-	1	2	mV
			Note 4	-	-	9	-	-	4	mV
Differential Input Voltage	V_{ID}	Keep All Inputs $\geq 0V$, or V^- (if used), (Note 5)	Note 4	-	-	36	-	-	36	V
Saturation Voltage	V_{SAT}	$V_{I^-} = 1V$, $V_{I^+} = 0V$, $I_{SINK} \leq 4mA$	$T_A = 25$	-	250	400	-	250	400	mV
			Note 4	-	-	700	-	-	700	mV
Common Mode Input Voltage Range	V_{ICR}	Note 6	$T_A = 25$	0	-	$V^+ - 1.5$	0	-	$V^+ - 1.5$	V
			Note 4	0	-	$V^+ - 2$	0	-	$V^+ - 2$	V
Input Offset Current	I_{IO}	$I_{I^+} - I_{I^-}$	$T_A = 25$	-	5	50	-	5	50	nA
			Note 4	-	-	150	-	-	150	nA
Input Bias Current	I_{IB}	I_{I^+} or I_{I^-} with Output in Linear Range	$T_A = 25$	-	25	250	-	25	250	nA
			Note 4	-	-	400	-	-	400	nA
Total Supply Current	I^+	$R_L = \infty$ on All Comparators	$T_A = 25$	-	0.8	2	-	0.8	2	mA
Output Leakage Current		$V_{I^+} \geq 1V$, $V_{I^-} = 0V$, $V_O = 5V$	$T_A = 25$	-	0.1	-	-	0.1	-	nA
		$V_{I^+} \geq 1V$, $V_{I^-} = 0V$, $V_O = 30V$	Note 4	-	-	1	-	-	1	μA
Output Sink Current		$V_{I^-} \geq 1V$, $V_{I^+} = 0V$, $V_O \leq 1.5V$	$T_A = 25$	6	16	-	6	16	-	mA
Voltage Gain	A_{OL}	$R_L \geq 15k\Omega$, $V^+ = 15V$	$T_A = 25$	50	200	-	50	200	-	V/mV
Large Signal Response Time		$V_I = \text{TTL Logic Swing}$, $V_{REF} = 1.4V$, $V_{RL} = 5V$, $R_L = 5.1k\Omega$	$T_A = 25$	-	300	-	-	300	-	ns
Response Time (Figures 3, 4)		$V_{RL} = 5V$, $R_L = 5.1k\Omega$	$T_A = 25$	-	1.3	-	-	1.3	-	μs

NOTES:

- Ambient Temperature (T_A) applicable over operating temperature range as shown below.
CA139, CA139A = $-55^\circ C$ to $125^\circ C$; CA239, CA239A = $-25^\circ C$ to $85^\circ C$; CA339, CA339A, LM339, LM339A = $0^\circ C$ to $70^\circ C$; LM2901, LM3302 = $-40^\circ C$ to $85^\circ C$.
- The comparator will provide a proper output state even if the positive swing of the inputs exceeds the power supply voltage level, if the other input remains within the common mode voltage range. The low input voltage state must not be less than $-0.3V$ (or $0.3V$ below the magnitude of the negative power supply, if used).
- The upper end of the common mode voltage range is $(V^+) - 1.5V$, but either or both inputs can go to $+30V$ without damage.

CA139, CA139A, CA239, CA239A, CA339, CA339A, LM339, LM339A, LM2901, LM3302

Electrical Specifications $V_+ = 5V$, Unless Otherwise Specified

PARAMETER	SYMBOL	TEST CONDITIONS	TEMP (°C)	LM2901			LM3302			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	V_{IO}	$V_{REF} = 1.4V$, $R_S = 0$, Output Switch Point $V \cong 1.4V$	$T_A = 25$	-	2	7	-	1	20	mV
			Note 4	-	-	15	-	-	40	mV
Differential Input Voltage	V_{ID}	Keep All Inputs $\geq 0V$, or V_- (if used), (Note 5)	Note 4	-	-	36	-	-	28	V
Saturation Voltage	V_{SAT}	$V_{I-} = 1V$, $V_{I+} = 0V$, $I_{SINK} \leq 4mA$	$T_A = 25$	-	250	400	-	250	500	mV
			Note 4	-	-	700	-	-	700	mV
Common Mode Input Voltage Range	V_{ICR}	Note 6	$T_A = 25$	0	-	$V_+ - 1.5$	0	-	$V_+ - 1.5$	V
			Note 4	0	-	$V_+ - 2$	0	-	$V_+ - 2$	V
Input Offset Current	I_{IO}	$I_{I+} - I_{I-}$	$T_A = 25$	-	5	50	-	3	100	nA
			Note 4	-	-	200	-	-	300	nA
Input Bias Current	I_{IB}	I_{I+} or I_{I-} with Output in Linear Range	$T_A = 25$	-	25	250	-	25	500	nA
			Note 4	-	-	500	-	-	1000	nA
Total Supply Current	I_+	$R_L = \infty$ on All Comparators	$T_A = 25$	-	0.8	2	-	0.8	2	mA
Output Leakage Current		$V_{I+} \geq 1V$, $V_{I-} = 0V$, $V_O = 5V$	$T_A = 25$	-	0.1	-	-	0.1	-	nA
		$V_{I+} \geq 1V$, $V_{I-} = 0V$, $V_O = 30V$	Note 4	-	-	1	-	-	1	μA
Output Sink Current		$V_{I-} \geq 1V$, $V_{I+} = 0V$, $V_O \leq 1.5V$	$T_A = 25$	6	16	-	6	16	-	mA
Voltage Gain	A_{OL}	$R_L \geq 15k\Omega$, $V_+ = 15V$	$T_A = 25$	25	100	-	2	30	-	V/mV
Large Signal Response Time		$V_I = TTL$ Logic Swing, $V_{REF} = 1.4V$, $V_{RL} = 5V$, $R_L = 5.1k\Omega$	$T_A = 25$	-	300	-	-	300	-	ns
Response Time (Figures 3, 4)		$V_{RL} = 5V$, $R_L = 5.1k\Omega$	$T_A = 25$	-	1.3	-	-	1.3	-	μs

Typical Performance Curves

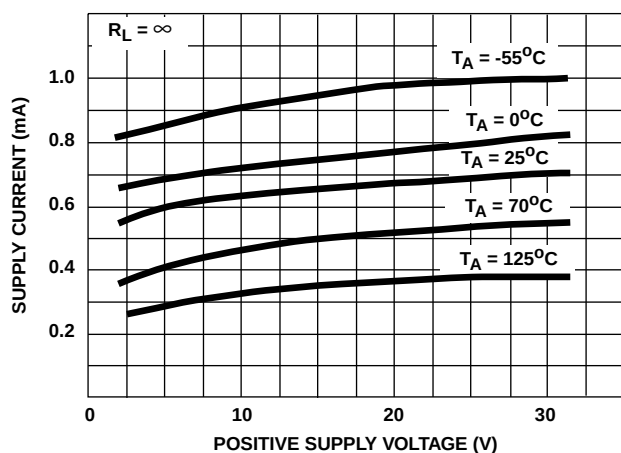


FIGURE 1. SUPPLY CURRENT vs SUPPLY VOLTAGE

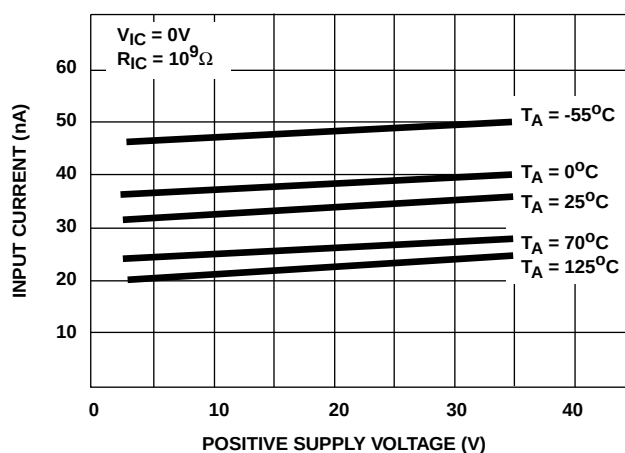


FIGURE 2. INPUT CURRENT vs SUPPLY VOLTAGE

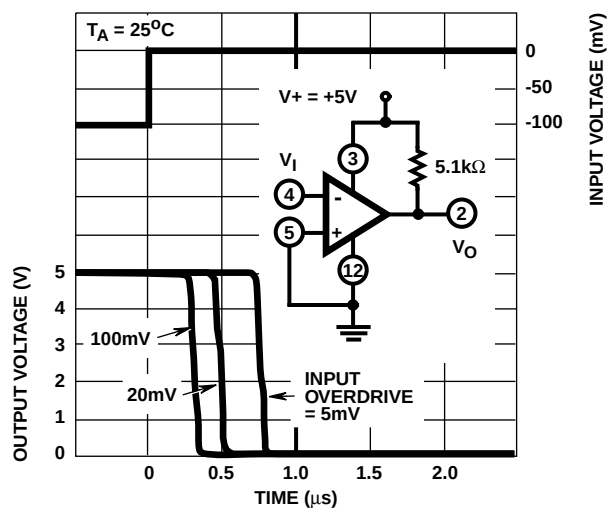


FIGURE 3. RESPONSE TIME FOR VARIOUS INPUT OVERDRIVES - NEGATIVE TRANSITION

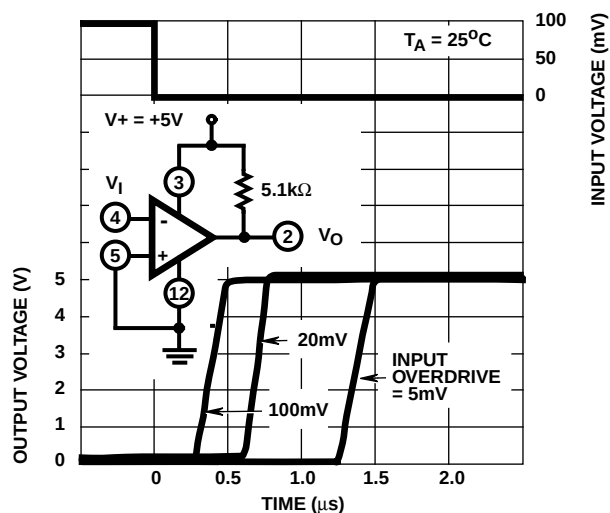


FIGURE 4. RESPONSE TIME FOR VARIOUS INPUT OVERDRIVES - POSITIVE TRANSITION

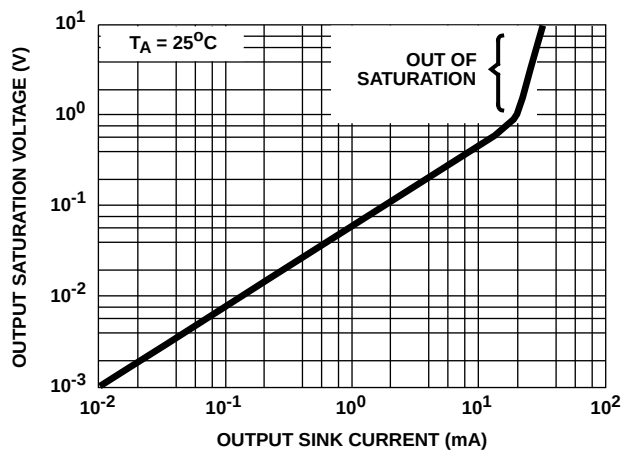
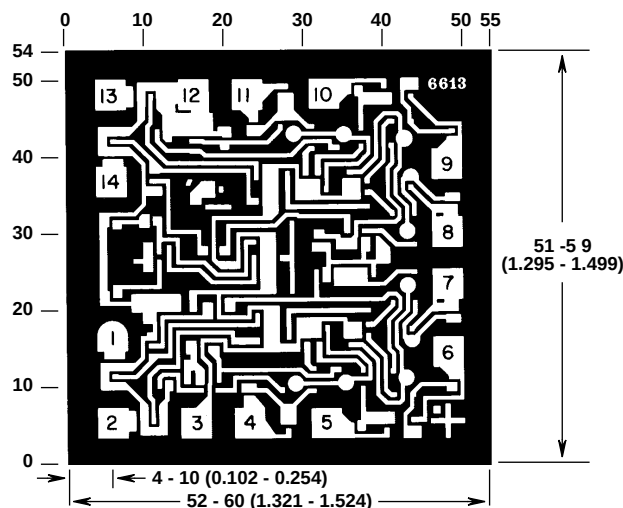


FIGURE 5. OUTPUT SATURATION VOLTAGE vs OUTPUT SINK CURRENT

Metallization Mask Layout



NOTE: Dimensions in parentheses are in mm and are derived from the basic in. dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

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